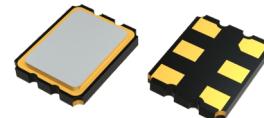


# 3.2 x 2.5 mm SMD CMOS Output Voltage Controlled Crystal Oscillator

## Feature

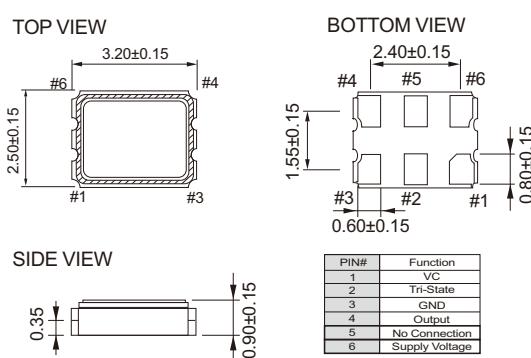
- Low power supply voltage: 3.3, 2.5 supply options.
- Frequency support from 10MHz to 250MHz.
- Low phase jitter typical: 0.8ps RMS from 12kHz TO 20MHz.
- Wide frequency control range. Tri-state enable/disable function
- Temperature range: -40 to 85°C operation
- Pb-free/ RoHS compliant



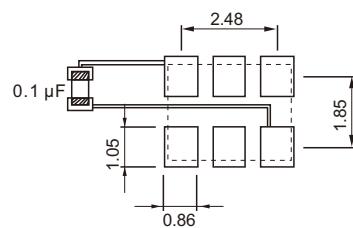
## Electrical Specifications

Parameter	CMOS				Unit
	3.3V		2.5V		
	Min.	Max.	Min.	Max.	
Supply Voltage Variation(VDD)	VDD-10%	VDD+10%	VDD-5%	VDD+5%	V
Frequency Range	10	250	10	250	MHz
Supply Current	-	50	-	45	mA
Output Level	Output High Output Low	2.97 -	- 0.33	2.25 -	V V
Transition Time ( 10% ~ 90% ) Rise/Fall Time +	-	1.0	-	1.0	nSec
Duty Cycle	45	55	45	55	%
Start Time	-	10	-	10	mSec
Tri-State (input to Pin 2)					
Enable	70%VDD	-	70%VDD	-	V
Disable	-	30%VDD	-	30%VDD	
Stand by Current	-	18	-	18	mA
Output Loading ( 10MHz to 200MHz )	-	15	-	15	pf
Output Loading ( 200MHz to 250MHz )	-	5	-	5	pf
Phase Noise	Typ.	Max.	Typ.	Max.	
At VDD=3.3V,fout=250MHz	1kHz offset	-107	-	-107	dBc/Hz
	10kHz offset	-111	-	-111	
	100kHz offset	-114	-	-114	
	1MHz offset	-125	-	-125	
	20MHz offset	-147	-	-147	
RMS Phase Jitter (12 kHz~20 MHz)	0.8	1.5	0.8	1.5	pSec
Control Voltage Center	1.65		1.25		V
Control Voltage Range	0.3	3	0.25	2.25	V
Frequency Pulling Range	±50	±150	±50	±150	ppm

## Dimension(mm)



## Solder Pad Layout(mm)



To ensure optimal oscillator performance, place a by-pass capacitor of 0.1 μF as close to the part as possible between Vdd and GND pads.

## FREQ. STABILITY vs. TEMP. RANGE

Temp. (°C)	ppm	±25	±50
-10 ~ +60	O	O	
-20 ~ +70	O	O	
-40 ~ +85	△	O	

o: Available Δ:Conditional X: Not available

Inclusive of calibration @ 25 °C, operating temperature range, input voltage variation, load variation, aging (1 st year), shock, and vibration